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Anomalous coercivity enhancement with temperature and tunable exchange bias in Gd and Ti co-doped $BiFeO_3$ multiferroics

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We have investigated the effect of temperature on magnetic properties of $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x = 0.00-0.20) multiferroic system. Unexpectedly, the coercive fields (H_c) of this multiferroic system increased with increasing temperature. The coercive fields and remanent magnetization were higher over a wide range of temperatures in sample x = 0.10 i.e. in sample having composition $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ than those of x = 0.00 and 0.20 compositions. Therefore, we have carried out temperature dependent magnetization experiments extensively for sample x = 0.10. The magnetic hysteresis loops at different temperatures exhibit an asymmetric shift towards the magnetic field axes which indicate the presence of exchange bias effect in this material system. The hysteresis loops were also carried out at temperatures 150 K and 250 K by cooling down the sample from 300 K in various cooling magnetic fields (H_{cool}). The exchange bias field (H_{EB}) values increased with H_{cool} and decreased with temperature. The H_{EB} values were tunable by field cooling at temperatures up to 250 K.

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I. INTRODUCTION

Multiferroic materials, in which ferromagnetic, ferroelectric, and/or ferroelastic orderings coexist, have attracted significant research interest since many years [1–5] due to their potential applications in data storage media, spintronics and ferroelectric random-access memories. The co-existence of 'ferro'-orders in multiferroics allows the possibility that the magnetization can be tuned by an applied electric field and vice versa. Among the limited choices offered by the multiferroic materials, $BiFeO_3$ (BFO), one of the single-phase multiferroic materials at room temperature, exhibits the co-existence of ferroelectric ordering with Curie temperature (T_C) of 1123 K and antiferromagnetic (AFM) ordering with a Néel temperature (T_N) of 643 K [6]. In $BiFeO_3$, magnetic ordering is of antiferromagnetic type, having a spiral modulated spin structure (SMSS) with an incommensurate long-wavelength period of 62 nm [6]. This spiral spin structure cancels the macroscopic magnetization and inhibits the observation of the linear magnetoelectric effect [7]. These problems ultimately limit the use of bulk $BiFeO_3$ in functional applications. Recent investigations demonstrated that in order to perturb the SMSS and improve the magnetic properties of $BiFeO_3$, partial substitution of Bi by rare-earth ions [8, 9] or alkaline-earth ions [10] and also substitution of Fe by transition metal ions [11, 12] is an effective route. It is also reported that simultaneous minor substitution of Bi and Fe in $BiFeO_3$ by ions such as La and Mn, La and Ti, Nd and Sc etc., respectively [13–15] also enhanced the magnetism and ferroelectricity in $BiFeO_3$.

Recently, we have observed that simultaneous substitution of Gd and Ti in place of Bi and Fe, respectively in $BiFeO_3$ multiferroics improved their morphological, dielectric and magnetic properties at room temperature [16]. Later on, another group also observed fascinating magnetic, optical and dielectric properties in this Gd and Ti co-doped $BiFeO_3$ ceramic system at room temperature [17]. Therefore, in this investigation, we were interested to conduct experiments on temperature dependence of magnetic properties of Gd and Ti co-doped $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x = 0.00-0.20) multiferroic materials. In particular, our interest is to investigate the effect of temperature on remanent magnetization, coercive fields and exchange bias (EB) fields of these bulk polycrystalline materials. Notably, the EB phenomenon which manifest itself by a shift of a magnetic hysteresis loop in systems containing ferromagnetic/antiferromagnetic bilayers has been studied extensively since many years due to its importance in spintronic applications [18]. The EB effect usually occurs when the system is cooled down in an external magnetic field through the magnetic ordering temperatures. Most of the research in this field is focused on specially prepared systems, however, recent investigations reported the presence of EB effect in perovskite manganites [19], cobaltites [20], Heusler alloys [21] and multiferroics [22]. Although EB has been observed in various bulk materials, the effect in most cases has been limited to far below room temperature (<100 K)[23, 24], thus making the systems less attractive for applications.

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In our previous investigation, the magnetization vs. magnetic field ($M-H$) hysteresis loops indicated the presence of exchange bias effect in the Gd and Ti co-doped $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x = 0.00-0.20) ceramics at room temperature although the biasing field was very small [16]. Therefore, in the present investigation, we have explored exchange bias effect in this material system at different temperatures ranging from 20 K to 300 K. We have also investigated the influence of cooling magnetic fields at temperatures 150 K and 250 K to observe a tunable exchange bias in sample composition $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ (this composition is referred as sample x = 0.10 throughout the manuscript).

II. EXPERIMENTAL DETAILS

The polycrystalline samples having compositions $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x = 0.00-0.20) were synthesized by using standard solid state reaction technique as was described in details in our previous investigation [16]. The powder materials and ceramic pellets sintered at 1100 K were used for magnetic characterization. The $M-H$ hysteresis loops of $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x = 0.00-0.20) multiferroic ceramics were carried out at different temperatures using a Superconducting Quantum Interference Device (SQUID) Magnetometer (Quantum Design MPMS-XL7, USA). The temperature dependent magnetization measurements were carried out both at zero field cooling (ZFC) and field cooling (FC) processes [25]. The magnetic hysteresis loops were also carried out at different temperatures by cooling down the sample from 300 K in various cooling fields (H_{cool}) [25].

III. RESULTS AND DISCUSSIONS

A. Magnetic characterization

For magnetic characterization, the M-H hysteresis loops of $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x = 0.00-0.20) samples were measured at different temperatures ranging from 20 K to 300 K with an applied magnetic field of up to ±50 kOe. As a typical example, the M-H loops of sample x = 0.10 (composition $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$) at different temperatures were presented in figure 1 (a). Figures 1 (b-h) demonstrate an enlarged view of the low-field M-H hysteresis loops of this sample measured at temperatures : (b) 20 K (c) 50 K (d) 100 K (e) 150 K (f) 200 K (g) 250 K and (h) 300 K. The hysteresis loops for the two other compositions were shown in the supplemental figures 1(S1) and 2(S2) [26]. It should be noted that the M-H hysteresis loops (figure 1, supplemental figures 1(S1) and 2(S2)) were carried out initially without applying any cooling magnetic field.

The coercive fields (H_c) and remanent magnetization (M_r) extracted from the hysteresis loops were quantified as: $H_c = (H_{c1} - H_{c2})/2$, where H_{c1} and H_{c2} are the left and right coercive fields [16, 27] and $M_r = |(M_{r1}-M_{r2})|/2$ where M_{r1} and M_{r2} are the magnetization with positive and negative points of intersection with H = 0, respectively [13]. Calculated values of H_c and M_r are plotted as a function of temperature in figures 2 (a and b) respectively for $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x =0.00-0.20) samples. Both the coercive fields and remanent magnetizations are higher for sample x = 0.10 than those for x = 0.00 and x = 0.20. Therefore, it is clear that the substitution of 10% Ti in place of Fe in $Bi_{0.9}Gd_{0.1}FeO_3$ compound significantly increased H_c and M_r. However, a further increment of Ti to 20% in place of Fe reduced H_c and M_r although their net values are still higher than that of Ti undoped $Bi_{0.9}Gd_{0.1}FeO_3$ sample. As was reported in our previous investigation [16], the larger values of H_c and M_r in sample x = 0.10 are related with the microstructure of the composition i.e. with homogeneous small grain size of the material. In the case of La and Nb co-substituted $BiFeO_3$ [28] and Pr and Zr co-substituted $BiFeO_3$ compounds [29], increase in coercive field with

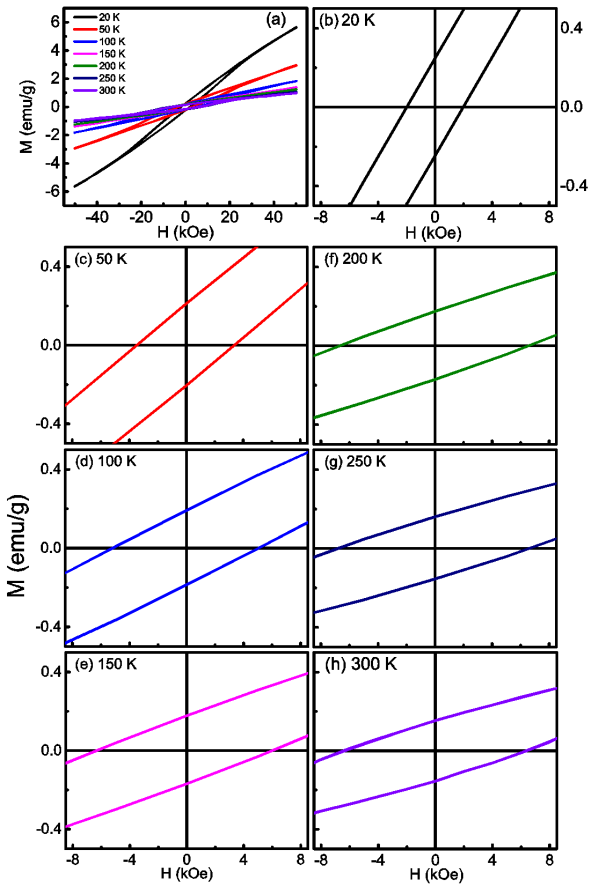

FIG. 1: (a) The $M-H$ hysteresis loops of sample x = 0.10 (composition $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$) carried out at different temperatures. (b-h) An enlarged view of the low-field M-H hysteresis loops of sample x = 0.10 obtained at temperatures : (b) 20 K (c) 50 K (d) 100 K (e) 150 K (f) 200 K (g) 250 K and (h) 300 K.

the substitution was also attributed to decrease in grain size. The value of H_c in these materials are much larger than that in pure $BiFeO_3$ [15, 16] and such a large value of coercivity in Gd and Ti co-substituted $BiFeO_3$ samples may be related to their magnetic anisotropy [15, 30, 31].

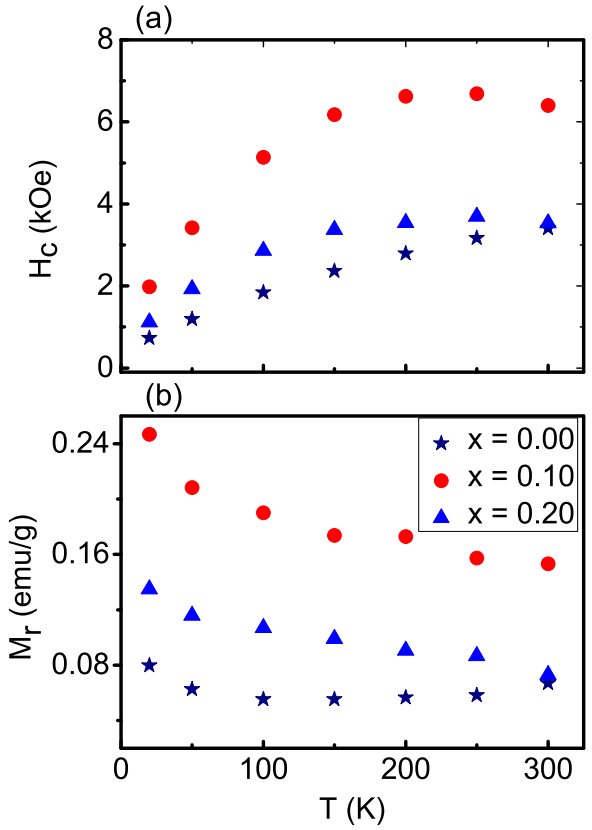

FIG. 2: The variation of (a) coercivity (H_c) and (b) remanent magnetization (M_r) as a function of temperature in $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x =0.00-0.20) compounds. Both H_c and M_r are higher over a wide range of temperatures in sample x =0.10.

The remarkable feature observed from figure 2(a) is that the coercivity of these ceramic samples increases with temperature. Figure 3 shows, as a typical example for x = 0.10 sample, that while the coercivity increases with increasing temperature, the maximum magnetization (M_s) at 50 kOe decreases with increasing temperature [32]. For all studied samples, the coercivity show a strong temperature dependency and the H_c values are significantly higher at room temperature than that at 20 K. For example, the H_c value at room temperature for sample x = 0.10 is three times higher than that at 20 K.

The usual trend in a typical magnetic system is for the coercivity to increase with decreasing temperature [33–35] since the anisotropy decreases much more sharply than does the magnetization with increasing temperature [36]. In similar multiferroic material systems, e.g. La doped $BiFeO_3$ [30, 31] and $LuFe_2O_4$ [37], the H_c values were found to increase at low temperature than that at room temperature. The unexpected decreasing trend of H_c at low temperature as compared with the room temperature values for all compositions investigated here may be explained by the presence of magnetoelectric coupling in these multiferroic materials [32, 36]. The presence of the magnetoelectric coupling produces additional contribution to the anisotropy that actually acts to decrease the effective magnetic anisotropy [32, 36]. If K_u is the uniaxial anisotropy constant in the absence of coupling effects and $K_u^{'}$ is the uniaxial anisotropy constant in the presence of magnetoelectric coupling, then

$$K_u^{'} = K_u - \chi_{\perp}\frac{(\beta P_z)^2}{2}$$

Here β is the homogeneous magnetoelectric co-efficient that is related to the Dzyaloshinsky Moriya magnetic field, $\chi_{\perp}$ is the magnetic susceptibility in the direction perpendicular to the antiferromagnetic vector, P_z is the spontaneous electric polarization [36, 38]. Thus the temperature variation in H_c is determined by the competition between the magnetic anisotropy and the magnetoelectric coupling [32, 36, 38].

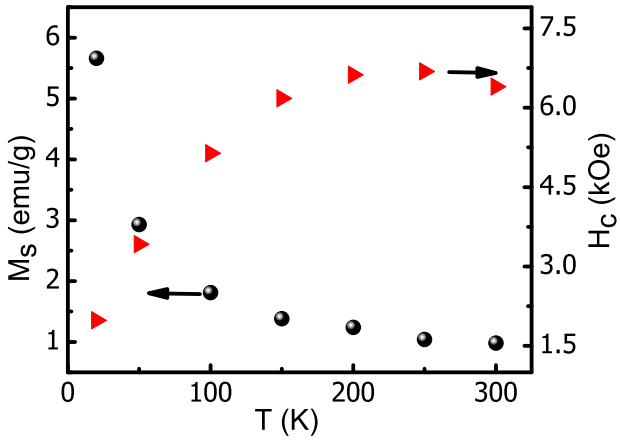

FIG. 3: The variation of M_s (the maximum magnetization at 50 kOe) and H_c as a function of temperature in sample x = 0.10 ($Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$).

The higher values of H_c and M_r in sample x = 0.10 than those of x = 0.00 and 0.20 compositions motivated us to investigate further its magnetic properties in details. Therefore, we have carried out the temperature dependence of the magnetization ($M - T$) of $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ bulk sample. The $M - T$ curves measured in ZFC and FC modes in the presence of 500 Oe applied magnetic field is shown in figure 4. In ZFC process, the sample is initially cooled from 300 K to the lowest achievable temperature and data were collected while heating in the presence of the applied field. On the other hand, in the FC mode, data values are collected

while cooling in the presence of the magnetic field which is commonly known as cooling magnetic field [22]. Here the temperature dependence magnetization measurements demonstrate clearly that both ZFC and FC curves of $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ ceramic coincide with each other without showing any bifurcation which indicates the absence of any spin flipping effect [39–41]. In similar multiferroic materials both the ZFC and FC curves were also found to coincide with each other [42, 43].

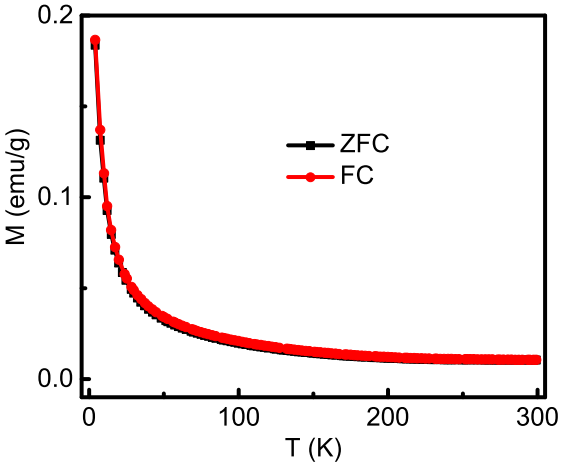

FIG. 4: The temperature dependence of magnetization ($M-T$ curves) of $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ sample measured in ZFC and FC processes in the presence of 500 Oe applied magnetic fields. Both ZFC and FC curves coincide with each other without showing any bifurcation.

As shown in figures 1(a-h), the room temperature $M-H$ hysteresis loop as well as the loops taken at other temperatures exhibit an asymmetric shift towards the magnetic field axes [25]. This is a signature of the presence of an exchange bias effect in multiferroic $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ material [16, 25, 44]. In the present investigation, the hysteresis loops of Gd and Ti co-doped $BiFeO_3$ ceramic system is unsaturated even with an applied magnetic field of up to ±50 kOe. which confirm the basic antiferromagnetic nature of the compounds. Notably, undoped $BiFeO_3$ possesses a very narrow hysteresis loop with a very small but non-zero remanent magnetization (0.0009 emu/g) and a coercive field of $\sim$ 110 Oe at room temperature [16]. Compared to pure $BiFeO_3$, the center of M-H loops of $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x = 0.00-0.20) compounds are wider (as shown typically in the enlarged view of sample x = 0.10, figures 1 (b-h)) which suggests a weak ferromagnetic nature [45] of this co-doped ceramic system. The weak ferromagnetic nature of this material system is also revealed from temperature dependent magnetization curves [45]. In this way we anticipate the co-existence

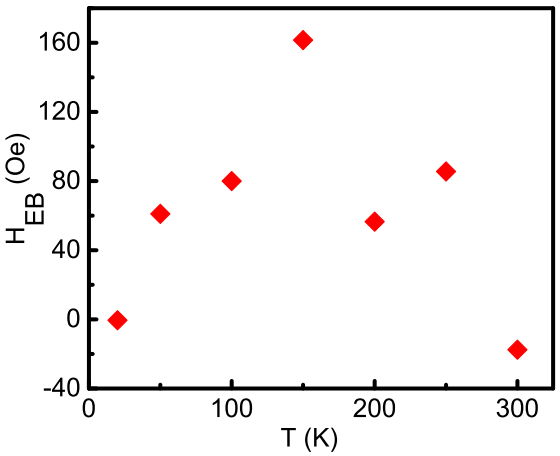

FIG. 5: The variation of exchange bias fields (H_{EB}) as a function of temperature in $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$. The H_{EB} values were calculated from the asymmetric shift of the M-H hysteresis loops of figures 1(b-h). The hysteresis loops were taken without applying a cooling magnetic field.

of strong-anisotropic ferri/ferromagnetic (FM) and antiferromagnetic domains in this multiferroic material system. As a consequence of the exchange coupling at interfaces between these multiple magnetic domains, it is expected that the system acts as a natural system for generating EB effect in $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ multiferroics [27, 33, 35, 46]. The exchange bias field (H_{EB}) from the loop asymmetry along the field axis can be quantified as $H_{EB} = -(H_{c1} + H_{c2})/2$ where H_{c1} and H_{c2} are the left and right coercive fields, respectively [25, 33]. The variation of H_{EB} as a function of temperature in $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ calculated from the asymmetric shift of the M-H hysteresis loops of figures 1(b-h) is shown in figure 5. The temperature dependence of H_{EB} for two other compositions were presented in the supplementary information (supplementary table 1) [26].

As was mentioned earlier, the EB effect usually occurs when the system is cooled down in an external magnetic field through the Néel temperature (T_N). It is worth mentioning that in $BiFeO_3$ ceramic system the exchange bias effect was observed without any magnetic-field-annealing process through T_N [47] which is the conventional method of inducing unidirectional anisotropy [48]. It has also been observed without using any alloy layers [49], however, then the biasing strength of $BiFeO_3$ is observed to be very weak with H_{EB} = 36 Oe [49] at room temperature. The exchange bias fields indicate the strength of the exchange coupling of an exchange bias system. As shown in figure 5, values of H_{EB} of $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ at 150 K and 250 K are higher than that at any other temperatures. The H_{EB} values shown in figure 5 is observed without applying any cooling magnetic field and therefore the biasing strength is

weak and random. In the case of a FM/AFM bilayer system, it is well known that cooling magnetic field plays an important role in establishing a strong unidirectional anisotropy due to the exchange coupling [50]. Hence, in the following experiments, the magnetic hysteresis loops of $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ material were carried out at temperatures 150 K and 250 K by cooling down the sample from 300 K in various cooling magnetic fields (H_{cool}) ranging from 20 kOe to 60 kOe. In each experiment related to cooling magnetic fields, the measuring magnetic fields were from -30 kOe to 30 kOe. The details of the loop asymmetry at different cooling fields and temperatures can be found in the supplementary figures 3(S3) and 4(S4) [26].

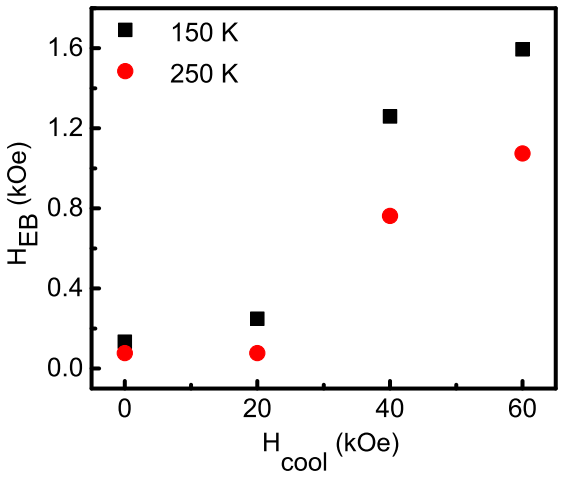

FIG. 6: Cooling field dependence of exchange bias field (H_{EB}) at 150 k and 250 K for $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ ceramic. The graph also demonstrates the dependency of H_{EB} on temperature.

The influence of cooling magnetic fields on exchange bias effect at temperatures 150 K and 250 K in $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ multiferroic material is illustrated in figure 6. The H_{EB} values increased significantly upon the application of cooling magnetic fields. For example, at temperature 250 K and cooling magnetic field 60 kOe, the biasing field increased more than twelve times than that for a cooling magnetic field of 20 kOe. During the field cooling experiments, the H_{EB} values reduced with increasing temperature, figure 6, which is similar to results reported in previous investigations [22, 51, 52]. The H_{EB} values are higher than those in related material systems [22, 53] specifically at high temperatures. In the present investigation, the temperature dependent ZFC and FC measurements (figure 4) demonstrate the absence of any bifurcation from 300 K down to 5 K and therefore, we had conducted the field cooling experiments by cooling the sample from 300 K down to 150 K and 250 K. By using the SQUID magnetometer (Quantum Design MPMS-XL7, USA), it was not possible to heat the sample above 300 K; therefore, the field cooling experiments were not possible to conduct by cooling down this sample through T_N which is around 520±10 K for $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ ceramic measured from temperature dependent dielectric measurements (data not shown here). As was mentioned earlier, the EB has been observed in various bulk materials, however, the effect in most cases has been limited to low temperatures [23, 24]. The observation of EB up to room temperature is of interest from the perspective of practical applications. Therefore, in future we intend to conduct field cooling experiments at room temperature by cooling $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ material through T_N which is above the room temperature.

The influence of H_{cool} on coercive fields were also measured at temperatures 150 K and 250 K and the results are displayed in table 1. Notably, in figures 2 and 3, we have shown the effect of temperature on H_c without applying any cooling magnetic field. Here in table 1, we have inserted the effect of cooling magnetic field on H_c and the measurements were carried out at two different temperatures close to room temperature. The exchange bias fields are strongly affected by cooling magnetic field as shown in figure 6, however, the H_c values (table 1) are influenced merely by a small extent. This is not unusual, in the case of NiFe/Co bilayers, similar effect was previously observed, i.e. the exchange bias field is strongly affected by cooling magnetic field whereas the H_c is weakly influenced [50].

TABLE I: The table shows the effect of cooling magnetic fields on H_c of $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ sample at temperatures 150 K and 250 K. Notably, the effect of temperatures on H_c of $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ sample without applying cooling magnetic fields was inserted in figure 2.

$T(k)$	H_c (kOe)			
	H_{cool} = 0 KOe	H_{cool} = 20 kOe	H_{cool} = 40 kOe	H_{cool} = 60 kOe
150	4.7	4.7	5.0	5.0
250	5.6	5.6	5.8	5.8

In our previous investigation [25], we have synthesized nanoparticles of the same composition i.e. of $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ with a mean size of 40-100 nm directly from their bulk powder by using the sonication technique described in Ref. [54]. In this specially prepared nanoparticle system, we have observed exchange bias effect and the magnitude of the exchange bias fields were also found to increase with cooling magnetic fields [25]. Obviously, the cooling field dependence of H_{EB} values of $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ bulk system were weaker than those of specially prepared $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ nanoparticles. For example, in both bulk and nanoparticle system the highest H_{EB} values were observed at temperature 150 K by applying 60 kOe cooling magnetic

field. At this temperature and cooling magnetic field, the H_{EB} value of the bulk system is 20 % less than that of nanoparticles having sizes 40-100 nm. This is worth noting as the preparation of bulk materials is comparatively easy and straightforward considering the multistep processing for the preparation of nanoparticles.

IV. CONCLUSIONS

We have observed a strong influence of temperature on coercive fields and exchange bias fields of Gd and Ti co-doped $BiFeO_3$ multiferroics. The coercive fields of this multiferroic system were enhanced anomalously with increasing temperature. The anomalous enhancement of the coercivity with increasing temperature and particularly the observation of the high values of H_c near/at room temperature may be of future use in potential applications where a coercivity stability at high temperature is crucially effective. We have also observed the presence of exchange bias effect due to the interface exchange coupling between FM and AFM domains of Gd and Ti co-doped $BiFeO_3$ material system. The magnitude of the exchange bias fields in bulk $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ were also found to increase with cooling magnetic field. This magnetically tunable exchange bias obtained in bulk multiferroic $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ material up to temperatures 250 K is promising, as most of the bulk materials show EB only far below room temperature. We anticipate that the presence of both exchange and magnetoelectric coupling in $Bi_{0.9}Gd_{0.1}Fe_{0.9}Ti_{0.1}O_3$ multiferroic material might be worthwhile for potential applications in novel multifunctional devices.

V. ACKNOWLEDGEMENTS

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[26] In supplemental figure 1(S1) (a) we show $M-H$ hysteresis loops of $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x = 0.00) sample measured at different temperatures. Figure 1(S1) (b-h) demonstrate the enlarged view of the low field hysteresis loops at temperatures: (b) 20 K (c) 50 K (d) 100 K (e) 150 K (f) 200 K (g) 250 K and (h) 300 K. Figure 2(S2) (a) shows $M-H$ hysteresis loops of $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x = 0.20) sample at different temperatures. Figure 2(S2) (b-h) present the enlarged view of the low field hysteresis loops at temperatures: (b) 20 K (c) 50 K (d) 100 K (e) 150 K (f) 200 K (g) 250 K and (h) 300 K. Figure 3(S3) (a-e) show the M-H hysteresis loops at T = 150

K carried out at different cooling magnetic fields. The M-H hysteresis loops at T = 250 K for different cooling magnetic fields are shown in figures 4(S4) (a-e). The asymmetric shifts toward the field axes are clearly visible from the enlarged views. Table 1 displays the variation of exchange bias fields, H_{EB} of $Bi_{0.9}Gd_{0.1}Fe_{1-x}Ti_xO_3$ (x = 0.00 and x = 0.20) at different temperatures.

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